**Key Parameters**

$V_{DRM} / V_{RRM}$	2800 - 3400 V
$I_{FAVM}$	175 A ( $T_C=100\text{ °C}$ )
$I_{FSM}$	4500 A
$V_{T0}$	0,9 V
$r_T$	1,8 m $\Omega$
$R_{thJC}$	0,17 K/W
Base plate	50 mm
Weight	800 g



For type designation please refer to actual short form catalog

<http://www.ifbip.com/catalog>

**Merkmale**

- Druckkontakt-Technologie für hohe Zuverlässigkeit
- Industrie-Standard-Gehäuse
- Elektrisch isolierte Bodenplatte

**Features**

- Pressure contact technology for high reliability
- Industrial standard package
- Electrically insulated base plate

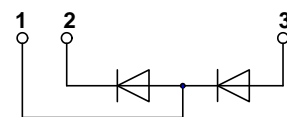
**Typische Anwendungen**

- Gleichrichter für Antriebsapplikationen
- Gleichrichter für UPS
- Batterieladegleichrichter

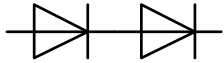
**Typical Applications**

- Rectifier for drives applications
- Rectifiers for UPS
- Battery chargers

	DMX code digit	DMX code digit quantity
content of customer DMX code		
type designation	1..18	18
serial number	19..23	5
internal production order number	24..31	8
material number	32..41	10
date code (YY/WW)	42..45	4
add on for date code	46	1



[www.ifbip.com](http://www.ifbip.com)  
[support@infineon-bip.com](mailto:support@infineon-bip.com)



# Datenblatt / Data sheet



**Netz-Dioden-Modul**  
**Rectifier Diode Module**

## DD175N

Infineon Technologies Bipolar  
GmbH & Co. KG

### DD175N

#### Elektrische Eigenschaften / Electrical properties

Höchstzulässige Werte / Maximum rated values

Periodische Spitzensperrspannung repetitive peak reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj\text{max}}$	$V_{RRM}$	2800 3200	3000 3400	V V <sup>1)</sup>
Stoßspitzensperrspannung non-repetitive peak reverse voltage	$T_{vj} = +25^{\circ}\text{C} \dots T_{vj\text{max}}$	$V_{RSM}$	2900 3300	3100 3500	V V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		$I_{FRMSM}$		350	A
Dauergrenzstrom average on-state current	$T_C = 100^{\circ}\text{C}$ $T_C = 78^{\circ}\text{C}$	$I_{FAVM}$		175 223	A A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj\text{max}}, t_p = 10\text{ms}$	$I_{FSM}$		4.500 4.000	A A
Grenzlastintegral $I^2t$ -value	$T_{vj} = 25^{\circ}\text{C}, t_p = 10\text{ms}$ $T_{vj} = T_{vj\text{max}}, t_p = 10\text{ms}$	$I^2t$		101.000 80.000	A <sup>2</sup> s A <sup>2</sup> s

#### Charakteristische Werte / Characteristic values

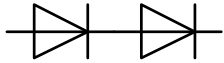
Durchlaßspannung on-state voltage	$T_{vj} = T_{vj\text{max}}, i_F = 600\text{A}$	$V_F$	max.	2,05	V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj\text{max}}$	$V_{(TO)}$		0,9	V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj\text{max}}$	$r_T$		1,8	m $\Omega$
Sperrstrom reverse current	$T_{vj} = T_{vj\text{max}}, V_R = V_{RRM}$	$i_R$	max.	20	mA
Isolations-Prüfspannung insulation test voltage	RMS, $f = 50\text{Hz}, t = 1\text{sec}$ RMS, $f = 50\text{Hz}, t = 1\text{min}$	$V_{ISOL}$		3,6 3,0	kV kV

#### Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resistance, junction to case	pro Modul / per Module, $\Theta = 180^{\circ}\text{sin}$ pro Zweig / per arm, $\Theta = 180^{\circ}\text{sin}$ pro Modul / per Module, DC pro Zweig / per arm, DC	$R_{thJC}$	max.	0,085 0,170 0,082 0,164	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	pro Modul / per Module pro Zweig / per arm	$R_{thCH}$	max.	0,02 0,04	$^{\circ}\text{C/W}$ $^{\circ}\text{C/W}$
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\text{max}}$		150	$^{\circ}\text{C}$
Betriebstemperatur operating temperature		$T_{c\text{op}}$		- 40...+150	$^{\circ}\text{C}$
Lagertemperatur storage temperature		$T_{stg}$		- 40...+150	$^{\circ}\text{C}$

1) 3400V auf Anfrage/ 3400V on request

prepared by:	A.G.	date of publication:	27.09.16
approved by:	M.S.	revision:	3.0



# Datenblatt / Data sheet




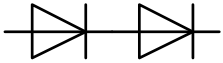
**Netz-Dioden-Modul**  
**Rectifier Diode Module**

## DD175N

Infineon Technologies Bipolar  
GmbH & Co. KG

### Mechanische Eigenschaften / Mechanical properties

Gehäuse, siehe Anlage case, see annex			Seite 4 page 4	
Si-Element mit Druckkontakt Si-pellet with pressure contact				
Innere Isolation internal insulation			AIN	
Anzugsdrehmoment für mechanische Anschlüsse mounting torque	Toleranz ±15%	M1	5	Nm
Anzugsdrehmoment für elektrische Anschlüsse terminal connection torque	Toleranz ±10%	M2	12	Nm
Gewicht weight		G	typ. 800	g
Kriechstrecke creepage distance			17	mm
Schwingfestigkeit vibration resistance	f = 50 Hz		50	m/s <sup>2</sup>
	file-No.		E 83335	



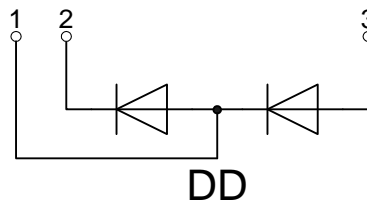
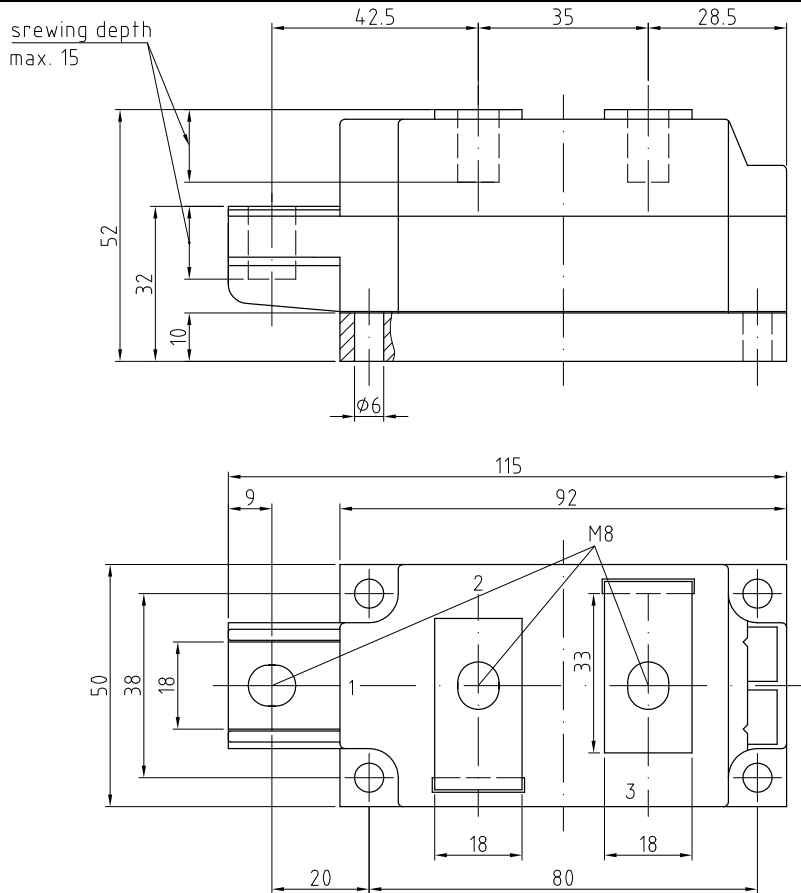
# Datenblatt / Data sheet

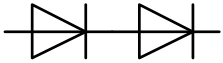


Netz-Dioden-Modul  
Rectifier Diode Module

## DD175N

Infineon Technologies Bipolar  
GmbH & Co. KG

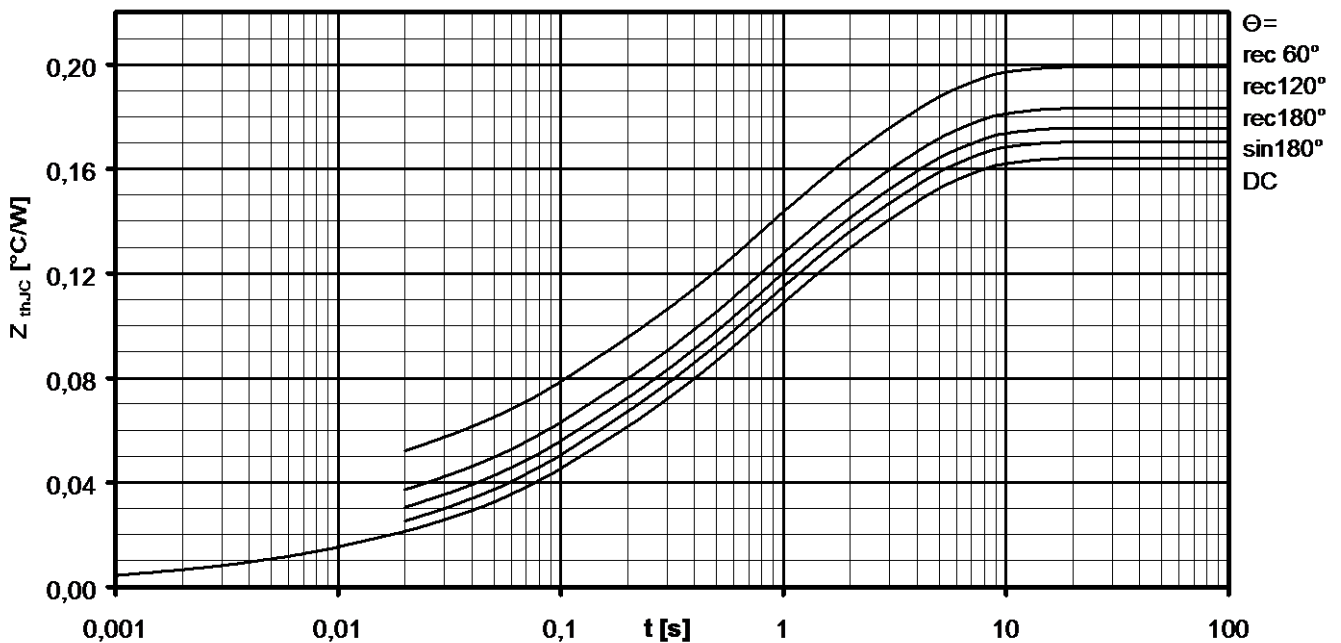




**Analytische Elemente des transienten Wärmewiderstandes  $Z_{thJC}$  für DC**  
**Analytical elements of transient thermal impedance  $Z_{thJC}$  for DC**

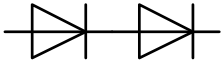
Pos. n	1	2	3	4	5	6	7
$R_{thn}$ [°C/W]	0,0039	0,0097	0,0291	0,0552	0,0661		
$T_n$ [s]	0,0008	0,008	0,085	0,54	2,85		

Analytische Funktion / Analytical function: 
$$Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} \left( 1 - e^{-\frac{t}{T_n}} \right)$$



Transienter innerer Wärmewiderstand je Zweig / Transient thermal impedance per arm  $Z_{thJC} = f(t)$

Parameter: Stromflußwinkel  $\Theta$  / Current conduction angle  $\Theta$



Natürliche Kühlung / Natural cooling  
3 Module pro Kühler / 3 modules per heatsink  
Kühler / Heatsink type: KM17 (60W)

**Analytische Elemente des transienten Wärmewiderstandes  $Z_{thCA}$**   
**Analytical elements of transient thermal impedance  $Z_{thCA}$**

Pos. n	1	2	3	4	5	6	7
$R_{thn}$ [°C/W]	0,0205	0,07905	1,535				
$T_n$ [s]	2,04	36,4	1340				

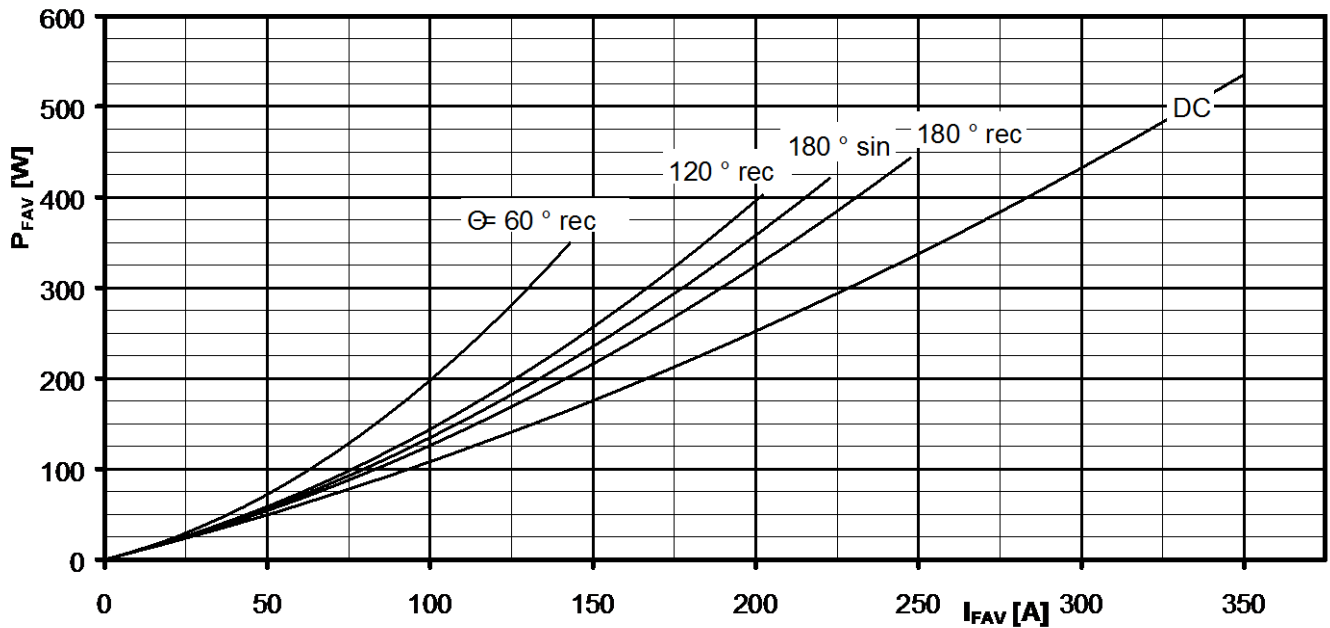
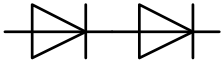
Verstärkte Kühlung / Forced cooling  
3 Module pro Kühler / 3 modules per heatsink  
Kühler / Heatsink type: KM17 (Papst 4650)

**Analytische Elemente des transienten Wärmewiderstandes  $Z_{thCA}$**   
**Analytical elements of transient thermal impedance  $Z_{thCA}$**

Pos. n	1	2	3	4	5	6	7
$R_{thn}$ [°C/W]	0,015	0,08	0,475				
$T_n$ [s]	4,11	40,4	458				

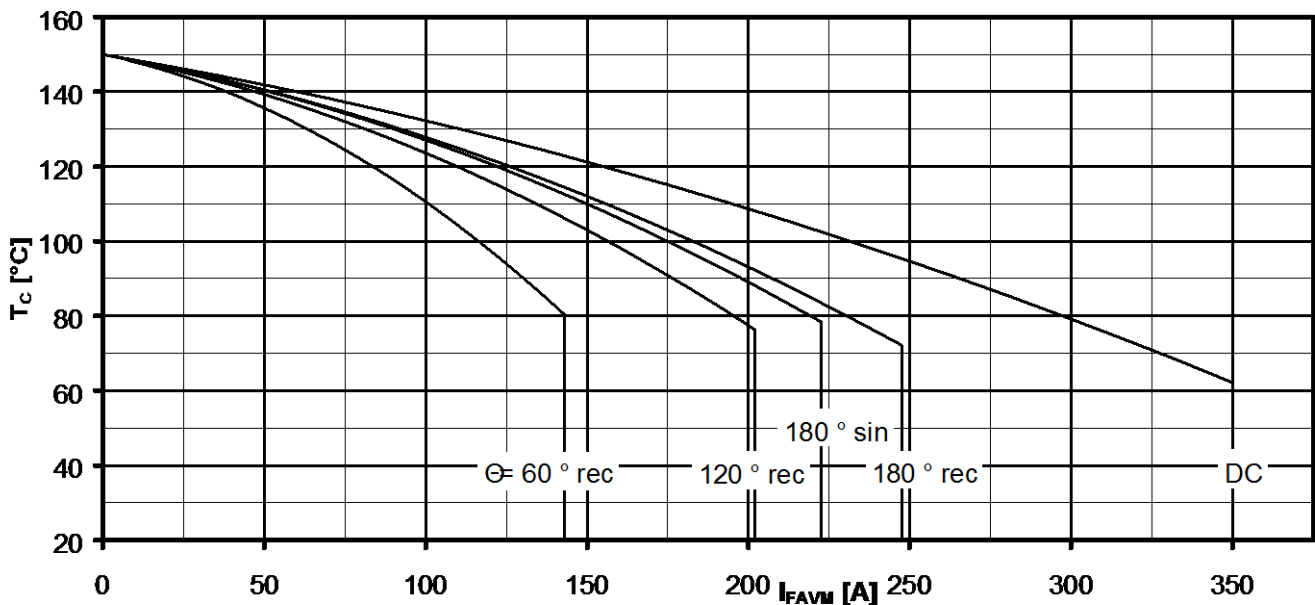
Analytische Funktion / Analytical function:

$$Z_{thCA} = \sum_{n=1}^{n_{max}} R_{thn} \left( 1 - e^{-\frac{t}{T_n}} \right)$$



Durchlassverlustleistung je Zweig / On-state power loss per arm  $P_{FAV} = f(I_{FAV})$

Parameter: Stromflußwinkel / Current conduction angle  $\Theta$

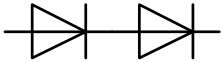


Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature  $T_C = f(I_{FAVM})$

Strombelastung je Zweig / Current load per arm

**Berechnungsgrundlage  $P_{TAV}$**  (Schaltverluste gesondert berücksichtigen)  
**Calculation base  $P_{TAV}$**  (switching losses should be considered separately)

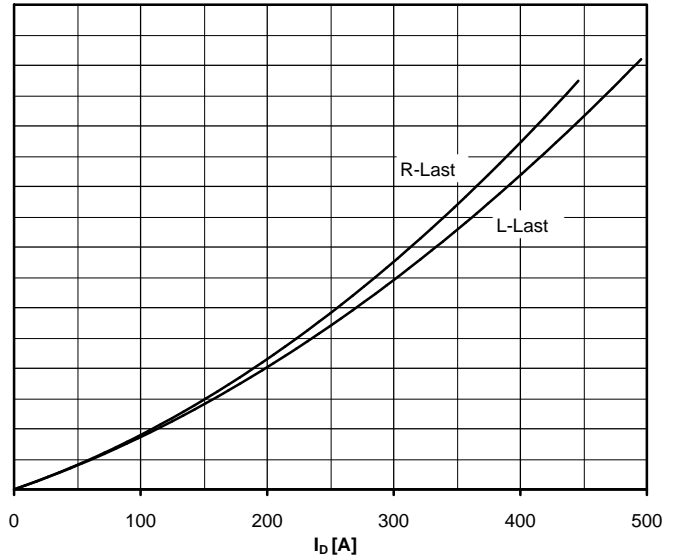
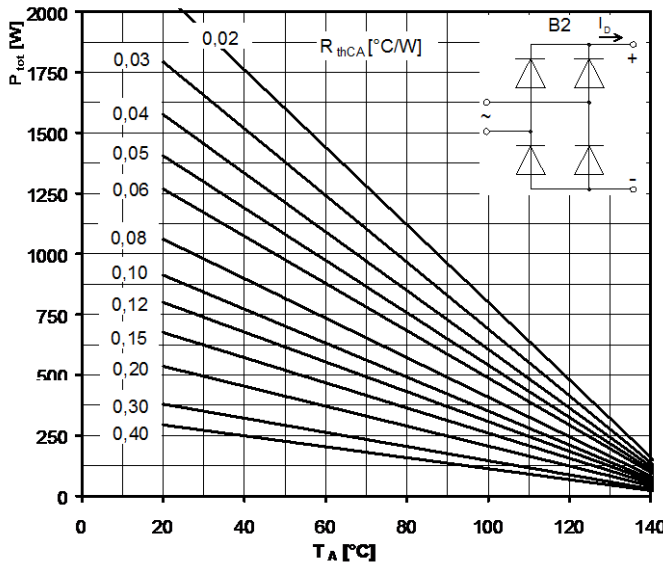
Parameter: Stromflußwinkel  $\Theta$  / Current conduction angle  $\Theta$



**Netz-Dioden-Modul**  
**Rectifier Diode Module**

## DD175N

Infineon Technologies Bipolar  
GmbH & Co. KG



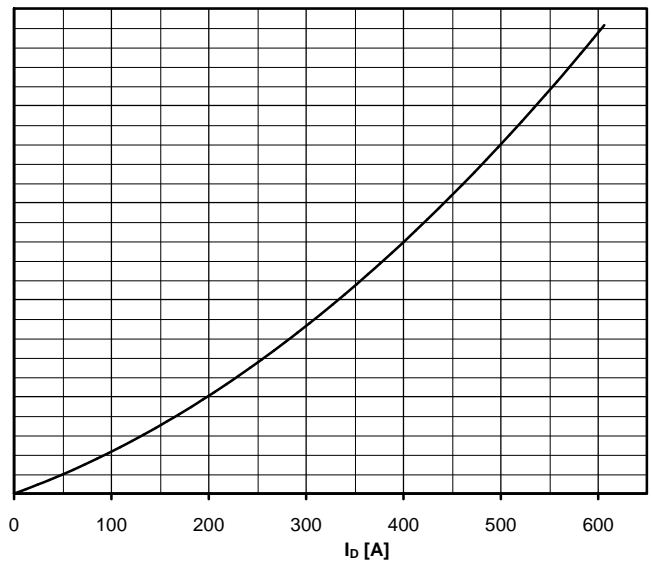
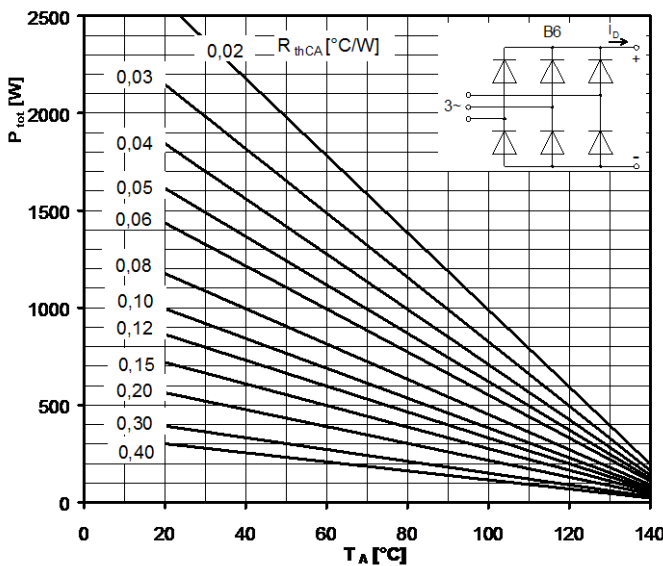
**Höchstzulässiger Ausgangsstrom / Maximum rated output current  $I_D$**

B2- Zweipuls-Brückenschaltung / Two-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit  $P_{tot}$

Parameter:

Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient  $R_{thCA}$



**Höchstzulässiger Ausgangsstrom / Maximum rated output current  $I_D$**

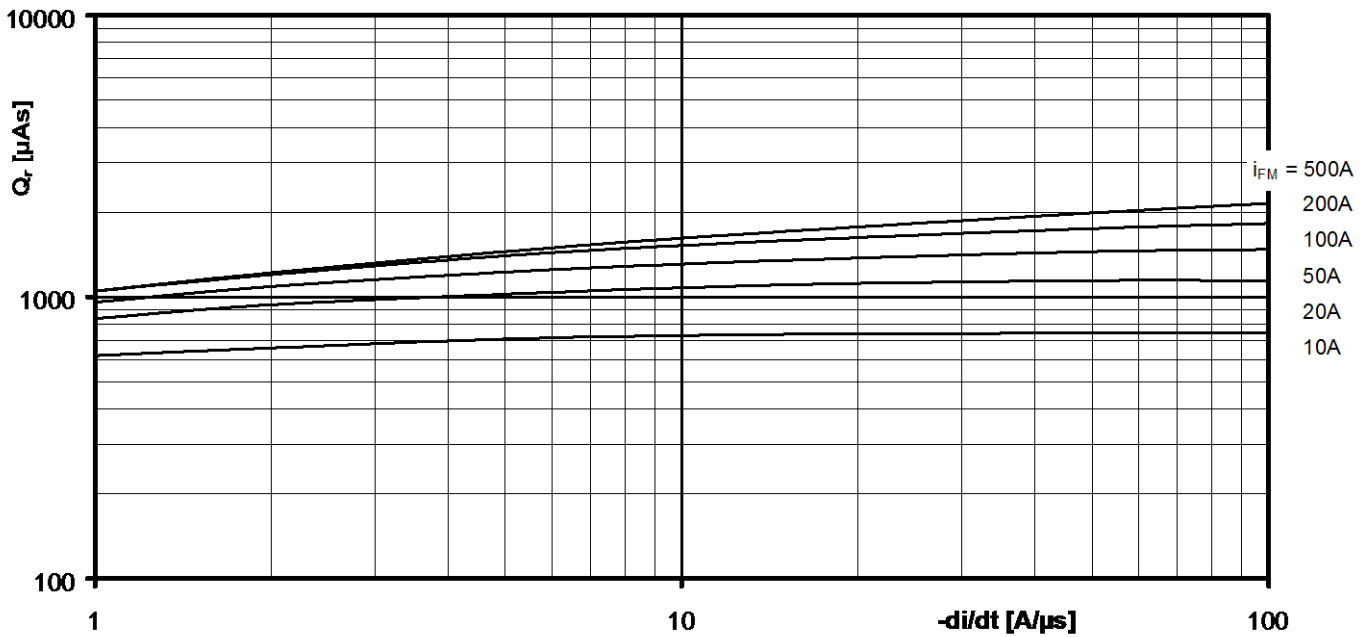
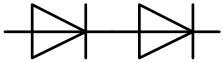
B6- Sechspuls-Brückenschaltung / Six-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit  $P_{tot}$

Parameter:

Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient  $R_{thCA}$

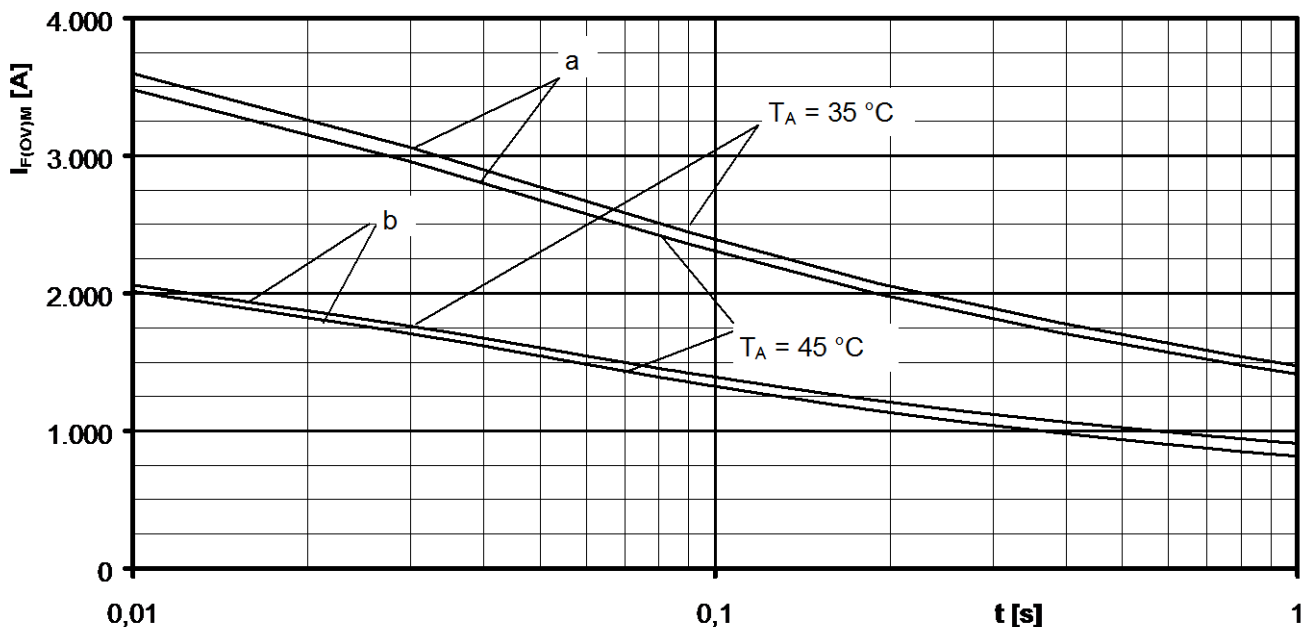




Sperrverzögerungsladung / Recovered charge  $Q_r = f(-di/dt)$

$$T_{vj} = T_{vjmax}, V_R \leq 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$$

Parameter: Durchlaßstrom / On-state current  $i_{FM}$



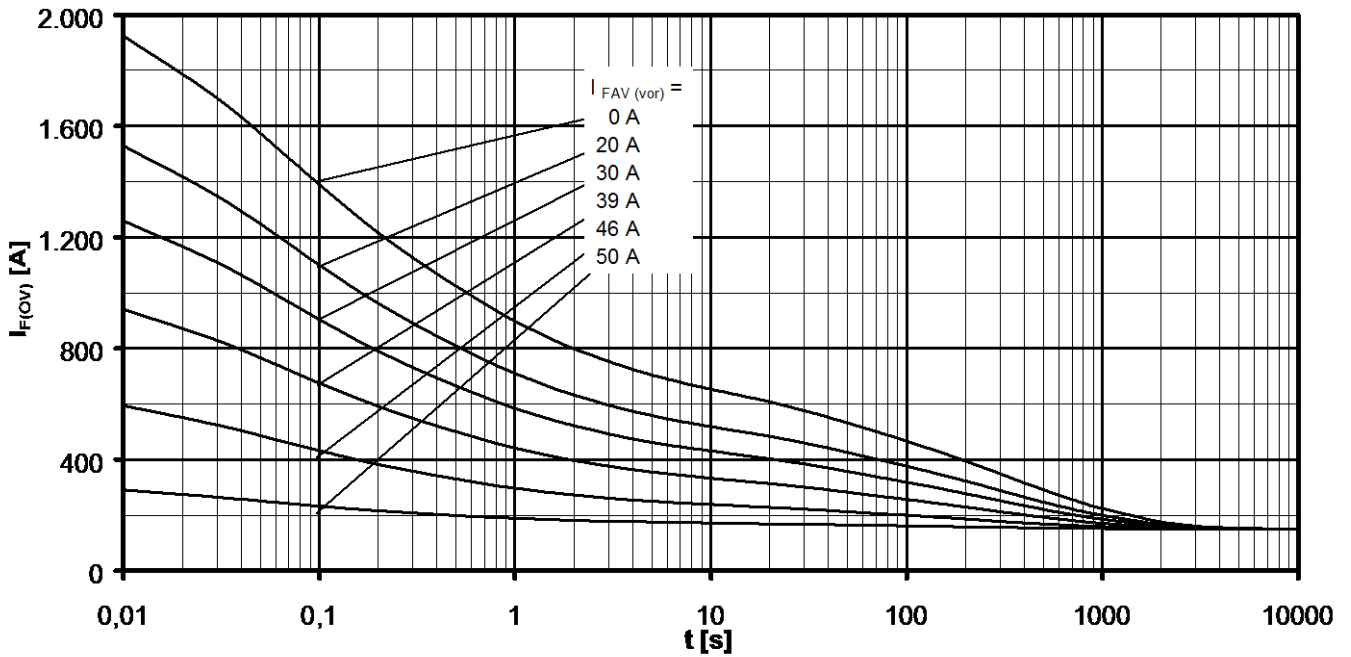
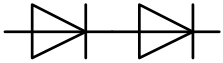
Grenzstrom je Zweig / Maximum overload on-state current per arm  $I_{F(OV)M} = f(t), V_{RM} = 0,8 V_{RRM}$

a: Leerlauf / No-load conditions

b: Vorlaststrom je Zweig / Pre-load current per arm  $I_{FAV(vor)} = I_{FAVM}$

$T_a = 35^\circ\text{C}$ , verstärkte Luftkühlung / Forced air cooling    Kühlkörper / Heatsink type: KM17 (Papst 4650)

$T_a = 45^\circ\text{C}$ , natürliche Luftkühlung / Natural air cooling    Kühlkörper / Heatsink type: KM17 (60W)

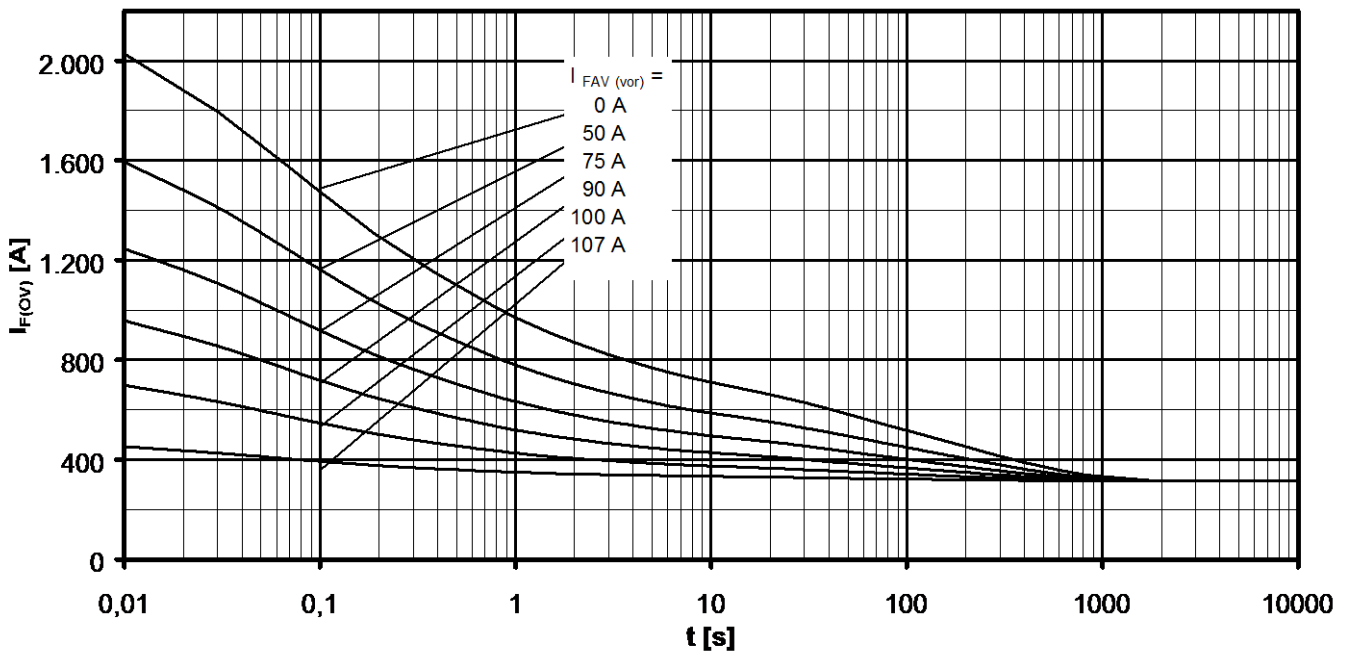


Überstrom je Zweig / Overload on-state current  $I_{F(ov)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit, 120° rectangular

Kühlkörper / Heatsink type KM17 (60W) Natürliche Kühlung bei / Natural cooling at  $T_A = 45^\circ\text{C}$

Parameter: Vorlaststrom je Zweig / Pre-load current per arm  $I_{FAV(vor)}$



Überstrom je Zweig / Overload on-state current  $I_{F(ov)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit 120° rectangular

Kühlkörper / Heatsink type KM17 (Papst 4650) Verstärkte Kühlung bei / Forced cooling at  $T_A = 35^\circ\text{C}$

Parameter: Vorlaststrom je Zweig / Pre-load current per arm  $I_{FAV(vor)}$